

## 4-bit Single Chip Microcomputer



- Core CPU Architecture
- Dot Matrix LCD Driver
- Serial Interface
- Programmable SVD Circuit

### ■ DESCRIPTION

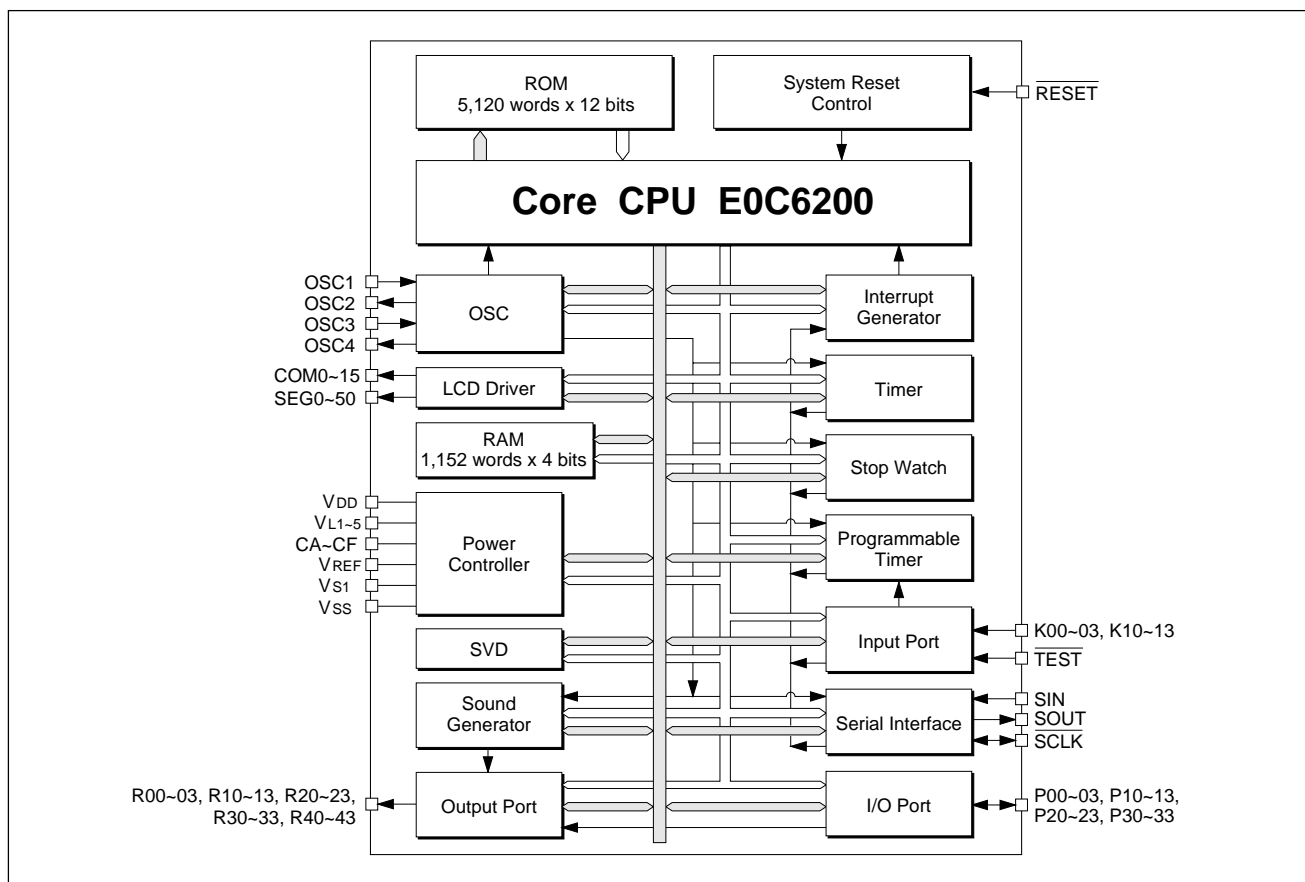
The E0C624C is a CMOS 4-bit single chip microcomputer with a Core CPU E0C6200 as main component, ROM, RAM, dot matrix LCD driver, serial interface, time base counter, SVD circuit, and others.

The E0C624C is most suitable for applications with equipment requiring dot matrix display functions.

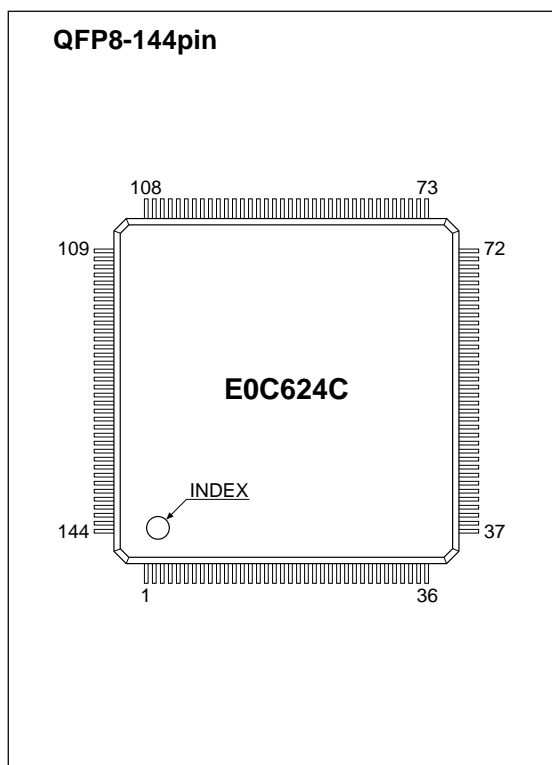
### ■ FEATURES

- CMOS LSI 4-bit parallel processing
- Clock ..... OSC1 crystal or CR oscillation circuit : 32.768kHz  
OSC3 ceramic or CR oscillation circuit : 2MHz (Max.)
- Instruction set ..... 108 instructions
- Instruction cycle time ..... Execution at 32.768kHz : 153μsec, 214μsec, 366μsec  
Execution at 2MHz : 2.5μsec, 3.5μsec, 6.0μsec
- ROM capacity ..... 5,120 × 12 bits
- RAM capacity ..... Data : 1,152 × 4 bits  
Segment : 204 × 4 bits
- External memory capacity ..... Read/write (RAM) : 64K × 4 bits (Max.)  
Read only (ROM) : 128K × 4 bits (Max.)
- Input port ..... 8 bits (pull-up resistors are available by mask option)
- Output port ..... 20 bits (can be switched to external memory bus and buzzer output by software)
- I/O port ..... 16 bits (can be switched to external memory bus, special outputs and serial I/O by software)
- Serial interface ..... 8-bit clock synchronous type
- Dot matrix LCD driver ..... 51 segments × 8 commons/16 commons
- Time base counter ..... 3 systems
- Programmable timer ..... 8-bit : 1 system, with event counter function
- Watchdog timer
- Programmable SVD circuit ..... 4 values programmable (2.2V to 4.2V)
- Sound generator ..... With digital envelope function, volume control function (8 levels)
- Interrupt ..... External : Input interrupt : 2 systems  
Internal : Clock timer interrupt : 3 systems  
Serial interface interrupt : 3 systems
- Supply voltage ..... 1.8V to 5.5V
- Current consumption ..... HALT mode (32.768kHz/3.0V) : 2.5μA (Typ.)  
OPERATING mode (2MHz/5.0V) : 1.0mA (Typ.)
- Package ..... QFP8-144pin (plastic)  
Die form

■ BLOCK DIAGRAM



■ PIN CONFIGURATION



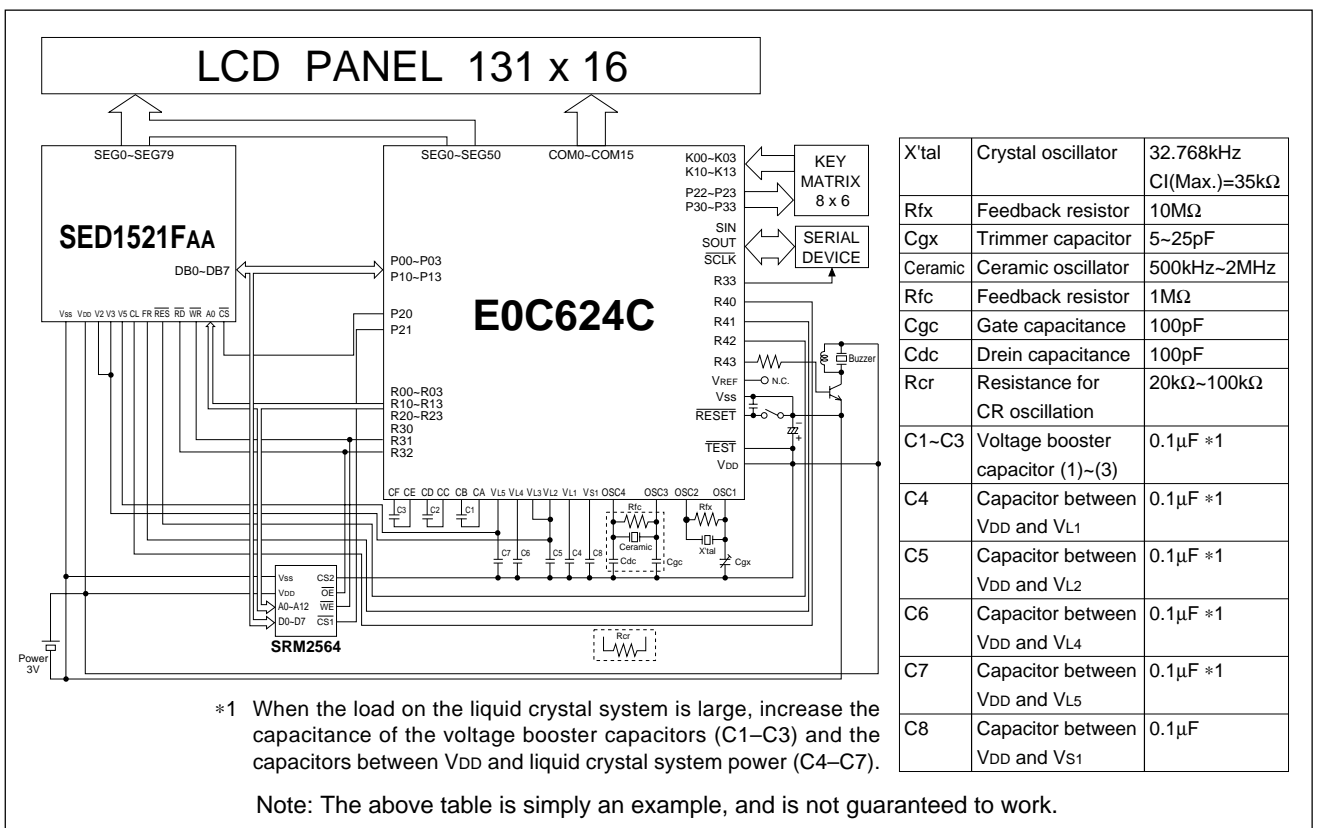
| No. | Pin name | No. | Pin name | No. | Pin name | No. | Pin name | No. | Pin name |
|-----|----------|-----|----------|-----|----------|-----|----------|-----|----------|
| 1   | CB       | 30  | SEG41    | 59  | SEG15    | 88  | P33      | 117 | R13      |
| 2   | CA       | 31  | SEG40    | 60  | SEG14    | 89  | P32      | 118 | R12      |
| 3   | N.C.     | 32  | SEG39    | 61  | SEG13    | 90  | P31      | 119 | R11      |
| 4   | COM0     | 33  | SEG38    | 62  | SEG12    | 91  | P30      | 120 | R10      |
| 5   | COM1     | 34  | SEG37    | 63  | SEG11    | 92  | P23      | 121 | R03      |
| 6   | COM2     | 35  | N.C.     | 64  | SEG10    | 93  | P22      | 122 | R02      |
| 7   | COM3     | 36  | N.C.     | 65  | SEG9     | 94  | P21      | 123 | R01      |
| 8   | COM4     | 37  | SEG36    | 66  | SEG8     | 95  | P20      | 124 | R00      |
| 9   | COM5     | 38  | SEG35    | 67  | SEG7     | 96  | P13      | 125 | VSS      |
| 10  | COM6     | 39  | SEG34    | 68  | SEG6     | 97  | N.C.     | 126 | RESET    |
| 11  | COM7     | 40  | SEG33    | 69  | SEG5     | 98  | P12      | 127 | TEST     |
| 12  | COM8     | 41  | SEG32    | 70  | SEG4     | 99  | P11      | 128 | OSC4     |
| 13  | COM9     | 42  | SEG31    | 71  | SEG3     | 100 | P10      | 129 | OSC3     |
| 14  | COM10    | 43  | SEG30    | 72  | SEG2     | 101 | P03      | 130 | VS1      |
| 15  | COM11    | 44  | SEG29    | 73  | SEG1     | 102 | P02      | 131 | OSC2     |
| 16  | COM12    | 45  | SEG28    | 74  | SEG0     | 103 | P01      | 132 | OSC1     |
| 17  | COM13    | 46  | SEG27    | 75  | N.C.     | 104 | P00      | 133 | N.C.     |
| 18  | COM14    | 47  | SEG26    | 76  | SCLK     | 105 | R43      | 134 | VDD      |
| 19  | N.C.     | 48  | SEG25    | 77  | SOUT     | 106 | R42      | 135 | VREF     |
| 20  | COM15    | 49  | SEG24    | 78  | SIN      | 107 | R41      | 136 | VL1      |
| 21  | SEG50    | 50  | N.C.     | 79  | K13      | 108 | R40      | 137 | VL2      |
| 22  | SEG49    | 51  | SEG23    | 80  | K12      | 109 | R33      | 138 | VL3      |
| 23  | SEG48    | 52  | SEG22    | 81  | K11      | 110 | R32      | 139 | VL4      |
| 24  | SEG47    | 53  | SEG21    | 82  | K10      | 111 | R31      | 140 | VL5      |
| 25  | SEG46    | 54  | SEG20    | 83  | K03      | 112 | R30      | 141 | CF       |
| 26  | SEG45    | 55  | SEG19    | 84  | N.C.     | 113 | R23      | 142 | CE       |
| 27  | SEG44    | 56  | SEG18    | 85  | K02      | 114 | R22      | 143 | CD       |
| 28  | SEG43    | 57  | SEG17    | 86  | K01      | 115 | R21      | 144 | CC       |
| 29  | SEG42    | 58  | SEG16    | 87  | K00      | 116 | R20      |     |          |

N.C. = No Connection

**■ PIN DESCRIPTION**

| Pin name                         | Pin No.               | In/Out | Function   |
|----------------------------------|-----------------------|--------|--|
| VDD                              | 134                   | I      | Power source (+) terminal  |
| VSS                              | 125                   | I      | Power source (-) terminal  |
| Vs1                              | 130                   | -      | Oscillation and internal logic system regulated voltage                                |
| VL1-VL5                          | 136-140               | -      | LCD system power (1/4 or 1/5 bias may be selected by mask option)                      |
| VREF                             | 135                   | O      | LCD system power test terminal   |
| CA-CF                            | 2, 1, 144-141         | -      | Booster capacitor connecting terminal  |
| OSC1                             | 132                   | I      | Crystal or CR oscillation input terminal (selected by mask option)                     |
| OSC2                             | 131                   | O      | Crystal or CR oscillation output terminal (selected by mask option)                    |
| OSC3                             | 129                   | I      | Ceramic or CR oscillation input terminal (selected by mask option)                     |
| OSC4                             | 128                   | O      | Ceramic or CR oscillation output terminal (selected by mask option)                    |
| K00-K03, K10-K13                 | 87-85, 83-79          | I      | Input terminal (Use of pull up resistor is selected by mask option)                    |
| P00-P03, P10-P13                 | 104-98, 96            | I/O    | I/O terminal (Setting for data bus may be selected by mask option)                     |
| P20-P23                          | 95-92                 | I/O    | I/O terminal (CS output may be selected by mask option)                                |
| P30-P33                          | 91-88                 | I/O    | I/O terminal   |
| R00-R03, R10-R13<br>R20-R23, R30 | 124-112               | O      | Output terminal (Setting for address bus may be selected by mask option)               |
| R31                              | 111                   | O      | Output terminal (DC, address or $\overline{WR}$ output may be selected by mask option) |
| R32                              | 110                   | O      | Output terminal (DC or $\overline{RD}$ output may be selected by mask option)          |
| R33                              | 109                   | O      | Output terminal (DC or $\overline{SRDY}$ output may be selected by mask option)        |
| R40                              | 108                   | O      | Output terminal (DC, CL or $\overline{FOUT}$ output may be selected by mask option)    |
| R41                              | 107                   | O      | Output terminal (DC or FR output may be selected by mask option)                       |
| R42                              | 106                   | O      | Output terminal (DC, BZ or FOUT output may be selected by mask option)                 |
| R43                              | 105                   | O      | Output terminal (DC or BZ output may be selected by mask option)                       |
| SIN                              | 78                    | I      | Serial interface input terminal  |
| SOUT                             | 77                    | O      | Serial interface output terminal   |
| SCLK                             | 76                    | I/O    | Serial interface clock input/output terminal   |
| SEG0-50                          | 74-51, 49-37<br>34-21 | O      | LCD segment output terminal  |
| COM0-15                          | 4-18, 20              | O      | LCD common output terminal   |
| RESET                            | 126                   | I      | Initial reset input terminal   |
| TEST                             | 127                   | I      | Test input terminal  |

**■ BASIC EXTERNAL CONNECTION DIAGRAM**



■ ELECTRICAL CHARACTERISTICS

● Absolute Maximum Ratings

(VDD=0V)

| Rating                       | Symbol | Value                       | Unit |
|------------------------------|--------|-----------------------------|------|
| Supply voltage               | Vss    | -7.0 to 0.5                 | V    |
| Input voltage (1)            | Vi     | Vss - 0.3 to 0.5            | V    |
| Input voltage (2)            | Viosc  | Vs1 - 0.3 to 0.5            | V    |
| Operating temperature        | Topr   | -20 to 70                   | °C   |
| Storage temperature          | Tstg   | -65 to 150                  | °C   |
| Soldering temperature / Time | Tsol   | 260°C, 10sec (lead section) | —    |
| Permissible dissipation *1   | Pd     | 250                         | mW   |

\*1: In case of plastic package (QFP8-144pin).

● Recommended Operating Conditions

(Ta=-20 to 70°C)

| Condition                     | Symbol | Remark  | Min.    | Typ.   | Max.  | Unit |   |
|-------------------------------|--------|---------|---------|--------|-------|------|---|
| Supply voltage                | Vss    | VDD=0V  | VSC="0" | -3.8   | -3.0  | -1.8 | V |
|                               |        |         | VSC="1" | -5.5   | -3.0  | -2.2 | V |
|                               |        |         | VSC="2" | -5.5   | -3.0  | -3.5 | V |
| Oscillation frequency (1)     | fosc1  |         | 20      | 32.768 | 50    | kHz  |   |
| Oscillation frequency (2)     | fosc3  | VSC="1" | 50      | 1,000  | 1,200 | kHz  |   |
| Oscillation frequency (3)     | fosc3  | VSC="2" | 50      | 2,000  | 2,300 | kHz  |   |
| Voltage booster capacitor (1) | C1     |         |         | 0.1    |       | μF   |   |
| Voltage booster capacitor (2) | C2     |         |         | 0.1    |       | μF   |   |
| Voltage booster capacitor (3) | C3     |         |         | 0.1    |       | μF   |   |
| Capacitor between VDD and VL1 | C4     |         |         | 0.1    |       | μF   |   |
| Capacitor between VDD and VL2 | C5     |         |         | 0.1    |       | μF   |   |
| Capacitor between VDD and VL4 | C6     |         |         | 0.1    |       | μF   |   |
| Capacitor between VDD and VL5 | C7     |         |         | 0.1    |       | μF   |   |
| Capacitor between VDD and Vs1 | C8     |         |         | 0.1    |       | μF   |   |

● DC Characteristics

(Unless otherwise specified: VDD=0V, VSS=-3.0V, VL1=-1.0V, VL2=-2.0V, VL4=-3.0V, VL5=-4.0V, fosc1=32.768kHz, fosc3=1MHz, Ta=25°C, C1-C8=0.047μF)

| Characteristic                | Symbol | Condition                                      | Min.    | Typ. | Max.    | Unit |
|-------------------------------|--------|--|---------|------|---------|------|
| High level input voltage      | VHIN   | VSS=-2.2 to -5.5V                              | 0.2•Vss |      | 0       | V    |
| Low level input voltage       | VLIN   | Ta=25°C  | Vss     |      | 0.8•Vss | V    |
| High level input voltage      | VHIN   | VSS=-2.2 to -5.5V                              | -0.2    |      | 0       | V    |
| Low level input voltage       | VLIN   | Ta=25°C  | Vss     |      | Vss+0.2 | V    |
| High level input current      | IiH    | VSS=-3.0V<br>ViH=0V                            | 0       |      | 0.5     | μA   |
| Low level input current (1)   | IiL1   | VSS=-3.0V<br>ViL1=Vss<br>With pull-up resistor | -45     |      | -15     | μA   |
| Low level input current (2)   | IiL2   | VSS=-3.0V<br>ViL2=Vss<br>No pull-up resistor   | -0.5    |      | 0       | μA   |
| High level output current (1) | IoH1   | VSS=-2.2V<br>VoH1=-0.5V                        |         |      | -1.0    | mA   |
| Low level output current (1)  | IoL1   | VSS=-2.2V<br>VoL1=Vss+0.5V                     | 4.0     |      |         | mA   |
| High level output current (2) | IoH2   | VSS=-2.2V<br>VoH2=-0.5V                        |         |      | -2.0    | mA   |
| Low level output current (2)  | IoL2   | VSS=-2.2V<br>VoL1=Vss+0.5V                     | 8.0     |      |         | mA   |
| Common output current         | IoH3   | VoH3=-0.05V                                    |         |      | -30     | μA   |
|                               | IoL3   | VoL3=VL5+0.05V                                 | 30      |      |         | μA   |
| Segment output current        | IoH4   | VoH4=-0.05V                                    |         |      | -10     | μA   |
|                               | IoL4   | VoL4=VL5+0.05V                                 | 10      |      |         | μA   |

● Analog Circuit Characteristics and Current Consumption

(Unless otherwise specified: V<sub>DD</sub>=0V, V<sub>SS</sub>=-3.0V, V<sub>L1</sub>=-1.0V, V<sub>L2</sub>=-2.0V, V<sub>L4</sub>=-3.0V, V<sub>L5</sub>=-4.0V, f<sub>osc1</sub>=32.768kHz, f<sub>osc3</sub>=1MHz, T<sub>a</sub>=25°C, C<sub>1</sub>-C<sub>8</sub>=0.047μF)

| Characteristic  | Symbol   | Condition   | Min.             | Typ.             | Max.             | Unit      |   |
|---|--|---|------------------|------------------|------------------|-----------|---|
| Liquid crystal drive voltage<br>(Normal mode)                   | VL1  | Connect 1MΩ load resistor between V <sub>DD</sub> and VL1<br>(No panel load)    | 1/2•VL2<br>-0.1  |                  | 1/2•VL2<br>×0.95 | V         |   |
|   | VL2  | Connect 1MΩ load resistor<br>between V <sub>DD</sub> and VL2<br>(No panel load) | LC="0"           |                  | -1.80            | Typ.×0.88 | V |
|   |  |   | LC="1"           |                  | -1.85            |           |   |
|   |  |   | LC="2"           |                  | -1.90            |           |   |
|   |  |   | LC="3"           |                  | -1.95            |           |   |
|   |  |   | LC="4"           |                  | -2.01            |           |   |
|   |  |   | LC="5"           |                  | -2.06            |           |   |
|   |  |   | LC="6"           |                  | -2.11            |           |   |
|   |  |   | LC="7"           | Typ.×1.12        | -2.17            |           |   |
|   |  |   | LC="8"           |                  | -2.22            |           |   |
|   |  |   | LC="9"           |                  | -2.27            |           |   |
|   |  |   | LC="10"          |                  | -2.32            |           |   |
|   |  |   | LC="11"          |                  | -2.38            |           |   |
|   |  |   | LC="12"          |                  | -2.43            |           |   |
|   |  |   | LC="13"          |                  | -2.48            |           |   |
| LC="14"   |  | -2.53   |                  |                  |                  |           |   |
| LC="15"   |  | -2.59   |                  |                  |                  |           |   |
| VL4   | Connect 1MΩ load resistor between V <sub>DD</sub> and VL4<br>(No panel load) | 3/2•VL2   |                  | 3/2•VL2<br>×0.95 | V                |           |   |
| VL5   | Connect 1MΩ load resistor between V <sub>DD</sub> and VL5<br>(No panel load) | 2•VL2   |                  | 2•VL2<br>×0.95   | V                |           |   |
| Liquid crystal drive voltage<br>(Heavy load<br>protection mode) | VL1  | Connect 1MΩ load resistor<br>between V <sub>DD</sub> and VL1<br>(No panel load) | LC="0"           |                  | -0.92            | Typ.×0.88 | V |
|   |  |   | LC="1"           |                  | -0.95            |           |   |
|   |  |   | LC="2"           |                  | -0.97            |           |   |
|   |  |   | LC="3"           |                  | -1.00            |           |   |
|   |  |   | LC="4"           |                  | -1.03            |           |   |
|   |  |   | LC="5"           |                  | -1.05            |           |   |
|   |  |   | LC="6"           |                  | -1.08            |           |   |
|   |  |   | LC="7"           | Typ.×1.12        | -1.11            |           |   |
|   |  |   | LC="8"           |                  | -1.13            |           |   |
|   |  |   | LC="9"           |                  | -1.16            |           |   |
|   |  |   | LC="10"          |                  | -1.18            |           |   |
|   |  |   | LC="11"          |                  | -1.21            |           |   |
|   |  |   | LC="12"          |                  | -1.24            |           |   |
|   |  |   | LC="13"          |                  | -1.26            |           |   |
|   | LC="14"  |   | -1.29            |                  |                  |           |   |
| LC="15"   |  | -1.32   |                  |                  |                  |           |   |
| VL2   | Connect 1MΩ load resistor between V <sub>DD</sub> and VL2<br>(No panel load) | 2•VL1   |                  | 2•VL1<br>×0.90   | V                |           |   |
| VL4   | Connect 1MΩ load resistor between V <sub>DD</sub> and VL4<br>(No panel load) | 3•VL1   |                  | 3•VL1<br>×0.90   | V                |           |   |
| VL5   | Connect 1MΩ load resistor between V <sub>DD</sub> and VL5<br>(No panel load) | 4•VL1   |                  | 4•VL1<br>×0.90   | V                |           |   |
| SVD voltage   | V <sub>SVD0</sub>  | SVC="0"   | -2.35            | -2.20            | -2.05            | V         |   |
|   | V <sub>SVD1</sub>  | SVC="1"   | -2.70            | -2.50            | -2.30            | V         |   |
|   | V <sub>SVD2</sub>  | SVC="2"   | -3.30            | -3.10            | -2.90            | V         |   |
|   | V <sub>SVD3</sub>  | SVC="3"   | -4.50            | -4.20            | -3.90            | V         |   |
| SVD circuit response time                                       | t <sub>SVD</sub>   |   |                  | 100              | μS               |           |   |
| Current consumption   | I <sub>hlt</sub>   | During HALT   | No panel load *1 | 2.5              | 5.0              | μA        |   |
|   | I <sub>EX1</sub>   | During operation at 32kHz   |                  | 6.5              | 9.0              | μA        |   |
|   | I <sub>EX2</sub>   | During operation at 1MHz  | No panel load *2 | 400              | 600              | μA        |   |
|   | I <sub>EX3</sub>   | During operation at 2MHz  | No panel load *3 | 1,000            | 1,500            | μA        |   |
| Current consumption<br>(OSC1•CR oscillation)                    | I <sub>hlt</sub>   | During HALT   | No panel load *4 | 20               | 70               | μA        |   |
|   | I <sub>EX1</sub>   | During operation at f <sub>osc1</sub>   |                  | 25               | 80               | μA        |   |
|   | I <sub>EX2</sub>   | During operation at 1MHz  |                  | 420              | 600              | μA        |   |
|   | I <sub>EX3</sub>   | During operation at 2MHz  | No panel load *5 | 1,000            | 1,500            | μA        |   |

\*1: SVD circuit: OFF status, VSC = "0", OSC1: oscillating with crystal, OSCC = "0"

\*2: SVD circuit: OFF status, VSC = "1", OSC1: oscillating with crystal

\*3: SVD circuit: OFF status, VSC = "2", OSC1: oscillating with crystal, V<sub>SS</sub> = -5.0V

\*4: SVD circuit: OFF status, VSC = "0" or "1", OSC1: oscillating with CR, OSCC = "0", R<sub>osc</sub> for OSC1 = 1.6MΩ

\*5: SVD circuit: OFF status, VSC = "2", OSC1: oscillating with CR, OSCC = "0", R<sub>osc</sub> for OSC1 = 1.6MΩ

● Oscillation Characteristics

The oscillation characteristics change depending on the conditions (components used, board pattern, etc.). Use the following characteristics as reference values.

**OSC1 crystal oscillation circuit**

(Unless otherwise specified:  $V_{DD}=0V$ ,  $V_{SS}=-3.0V$ , Crystal: C-002R ( $C_I=35k\Omega$ ),  $C_{Gx}=25pF$ ,  $C_{Dx}=\text{built-in}$ ,  $R_{fX}=10M\Omega$ ,  $V_{SC}="0"$ ,  $T_a=25^\circ C$ )

| Characteristic                     | Symbol                    | Condition                            | Min. | Typ. | Max. | Unit      |
|------------------------------------|---------------------------|--------------------------------------|------|------|------|-----------|
| Oscillation start time             | $t_{sta}$                 | $V_{SS}=-2.2$ to $-5.5V$             |      |      | 5    | Sec       |
| Built-in capacitance (drain)       | $C_D$                     | Package as assembled                 |      | 22   |      | pF        |
|                                    |                           | Bare chip                            |      | 21   |      | pF        |
| Frequency/voltage deviation        | $\partial f/\partial V$   | $V_{SS}=-2.2$ to $-5.5V$             |      |      | 5    | ppm       |
| Frequency/IC deviation             | $\partial f/\partial IC$  |                                      | -10  |      | 10   | ppm       |
| Frequency adjustment range         | $\partial f/\partial C_G$ | $C_G=5$ to $25pF$                    | 35   | 45   |      | ppm       |
| Harmonic oscillation start voltage | $V_{hho}$                 | $C_G=5pF$                            |      |      | -5.5 | V         |
| Permitted leak resistance          | $R_{leak}$                | Between OSC1 and $V_{DD}$ , $V_{S1}$ | 200  |      |      | $M\Omega$ |

**OSC1 CR oscillation circuit**

(Unless otherwise specified:  $V_{DD}=0V$ ,  $V_{SS}=-3.0V$ ,  $V_{SC}="0"$  or  $"1"$ ,  $T_a=25^\circ C$ )

| Characteristic              | Symbol                  | Condition                | Min.            | Typ. | Max.             | Unit |
|-----------------------------|-------------------------|--------------------------|-----------------|------|------------------|------|
| Oscillation start time      | $t_{sta}$               | $V_{SS}=-2.2$ to $-5.5V$ |                 |      | 3                | mS   |
| Frequency/voltage deviation | $\partial f/\partial V$ | $V_{SS}=-2.2$ to $-5.5V$ | -5              |      | 5                | %    |
| Oscillation frequency       | $f_{CR}$                | $R_{osc}=1.6M\Omega$     | $32\times 70\%$ | 32   | $32\times 130\%$ | kHz  |

**OSC3 CR oscillation circuit (1)**

(Unless otherwise specified:  $V_{DD}=0V$ ,  $V_{SS}=-3.0V$ ,  $V_{SC}="1"$ ,  $T_a=25^\circ C$ )

| Characteristic              | Symbol                  | Condition                | Min.             | Typ. | Max.              | Unit |
|-----------------------------|-------------------------|--------------------------|------------------|------|-------------------|------|
| Oscillation start time      | $t_{sta}$               | $V_{SS}=-2.2$ to $-5.5V$ |                  |      | 3                 | mS   |
| Frequency/voltage deviation | $\partial f/\partial V$ | $V_{SS}=-2.2$ to $-5.5V$ | -5               |      | 5                 | %    |
| Oscillation frequency       | $f_{CR}$                | $R_{osc}=40k\Omega$      | $860\times 70\%$ | 860  | $860\times 130\%$ | kHz  |

**OSC3 CR oscillation circuit (2)**

(Unless otherwise specified:  $V_{DD}=0V$ ,  $V_{SS}=-5.0V$ ,  $V_{SC}="2"$ ,  $T_a=25^\circ C$ )

| Characteristic              | Symbol                  | Condition                | Min.             | Typ. | Max.              | Unit |
|-----------------------------|-------------------------|--------------------------|------------------|------|-------------------|------|
| Oscillation start time      | $t_{sta}$               | $V_{SS}=-3.5$ to $-5.5V$ |                  |      | 3                 | mS   |
| Frequency/voltage deviation | $\partial f/\partial V$ | $V_{SS}=-3.5$ to $-5.5V$ | -5               |      | 5                 | %    |
| Oscillation frequency       | $f_{CR}$                | $R_{osc}=20k\Omega$      | $1.7\times 70\%$ | 1.7  | $1.7\times 130\%$ | MHz  |

**OSC3 ceramic oscillation circuit (1)**

(Unless otherwise specified:  $V_{DD}=0V$ ,  $V_{SS}=-3.0V$ ,  $V_{SC}="1"$ , Ceramic: CSB 1000J (Murata Mfg. Co.),  $C_{Gc}=C_{Dc}=100pF$ ,  $R_{fC}=1M\Omega$ ,  $T_a=25^\circ C$ )

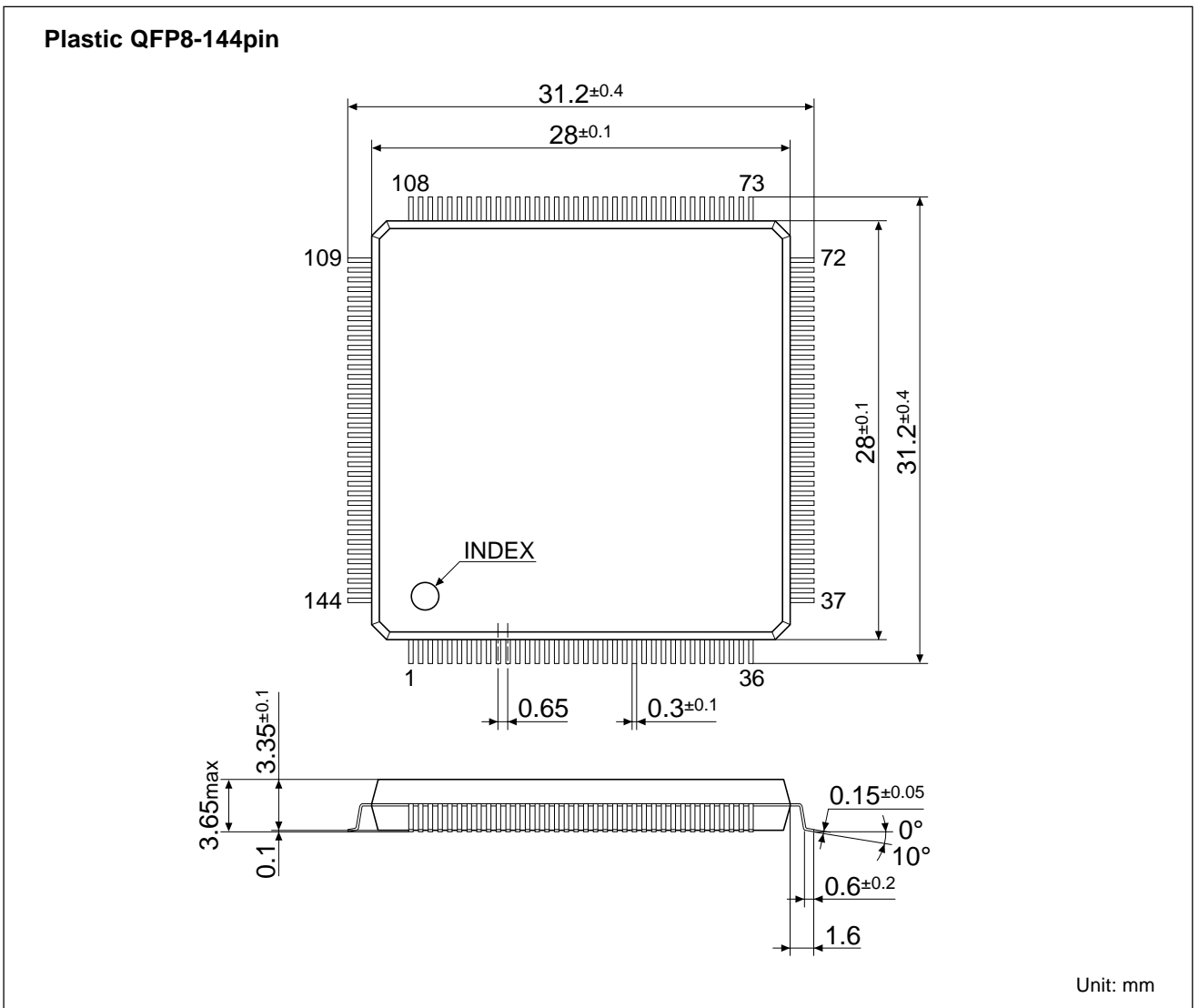
| Characteristic              | Symbol                  | Condition                | Min. | Typ. | Max. | Unit |
|-----------------------------|-------------------------|--------------------------|------|------|------|------|
| Oscillation start time      | $t_{sta}$               | $V_{SS}=-2.2$ to $-5.5V$ |      |      | 3    | mS   |
| Frequency/voltage deviation | $\partial f/\partial V$ | $V_{SS}=-2.2$ to $-5.5V$ | -3   |      | 3    | %    |

**OSC3 ceramic oscillation circuit (2)**

(Unless otherwise specified:  $V_{DD}=0V$ ,  $V_{SS}=-5.0V$ ,  $V_{SC}="2"$ , Ceramic: CSA 2.00MG (Murata Mfg. Co.),  $C_{Gc}=C_{Dc}=100pF$ ,  $R_{fC}=1M\Omega$ ,  $T_a=25^\circ C$ )

| Characteristic              | Symbol                  | Condition                | Min. | Typ. | Max. | Unit |
|-----------------------------|-------------------------|--------------------------|------|------|------|------|
| Oscillation start time      | $t_{sta}$               | $V_{SS}=-3.5$ to $-5.5V$ |      |      | 3    | mS   |
| Frequency/voltage deviation | $\partial f/\partial V$ | $V_{SS}=-3.5$ to $-5.5V$ | -3   |      | 3    | %    |

■ PACKAGE DIMENSIONS



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